

# UNISONIC TECHNOLOGIES CO., LTD

UD2195

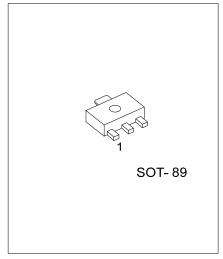
**Preliminary** 

### NPN SILICON TRANSISTOR

# NPN EPITAXIAL PLANAR TRANSISTOR

#### ■ DESCRIPTION

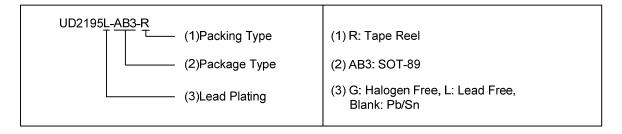
- \* The UTC **UD2195** is designed for use in general purpose amplifier and low speed switching application.
  - \* Pb-free package process is adopted.



Lead-free: UD2195L Halogen-free: UD2195G

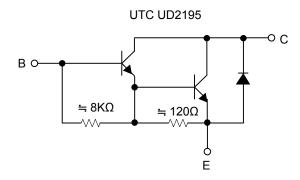
### ■ ORDERING INFORMATION

Ordering Number			Dookogo	Pin Assignment			Dooking	
Normal	Lead Free	Halogen Free	Package	1	2	3	Packing	
UD2195-AB3-R	UD2195L-AB3-R	UD2195G-AB3-R	SOT-89	В	С	Е	Tape Reel	



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# ■ EQUIVALENT CIRCUIT



- B: Base C: Collector
- E: Emitter

# ■ ABSOLUTE MAXIMUM RATING (T<sub>a</sub>=25°C)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		$V_{CBO}$	130	V	
Collector-Emitter Voltage		$V_{CEO}$	120	V	
Emitter-Base Voltage		$V_{EBO}$	5	V	
Collector Current	DC	Ic	4	Α	
	Pulse(Note 2)		6		
Collector Dissipation		Pc	0.6	W	
Junction Temperature		$T_J$	150	$^{\circ}\!\mathbb{C}$	
Storage Temperature		$T_{STG}$	-55 ~ <b>+</b> 150	$^{\circ}\mathbb{C}$	

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse test: Pulse Width ≤ 350µs, Duty Cycle ≤ 2%

#### ■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction-to-Ambient	$\theta_{JA}$	208	°C/W	

#### ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> =100μA, I <sub>E</sub> =0	130			V	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	120			V	
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	V <sub>CE</sub> =4V, I <sub>C</sub> =2A			2.8	٧	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =100V, I <sub>E</sub> =0			1	mA	
Collector Cutoff Current	I <sub>CEO</sub>	V <sub>CE</sub> =50V, I <sub>B</sub> =0			2	mA	
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{EB}$ =5 $V$ , $I_{C}$ =0			2	mΑ	
ON CHARACTERISTICS							
DC Current Gain (Note)	h <sub>FE</sub>	V <sub>CE</sub> =4V, I <sub>C</sub> =1A	1000				
DC Current Gain (Note)		V <sub>CE</sub> =4V, I <sub>C</sub> =2A	500				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I <sub>C</sub> =2A, I <sub>B</sub> =2mA			2	V	
SMALL-SIGNAL CHARACTERISTICS							
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0A, f=1MHz			200	pF	

Note: Pulse test: Pulse Width ≤ 380μs, Duty Cycle ≤ 2%

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